

/ Descriptions

Silicon PNP transistor in a TO-251 Plastic Package.

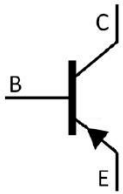
/ Features

High f_T , complementary pair with 2SC5171I.

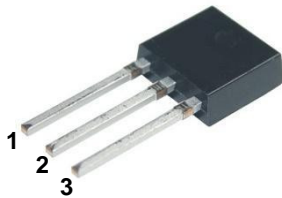
/ Applications

General power and driver stage amplifier applications.

/ Equivalent Circuit



/ Pinning



PIN1 Base PIN 2 Collector PIN 3 Emitter

/ h_{FE} Classifications & Marking

See Marking Instructions.

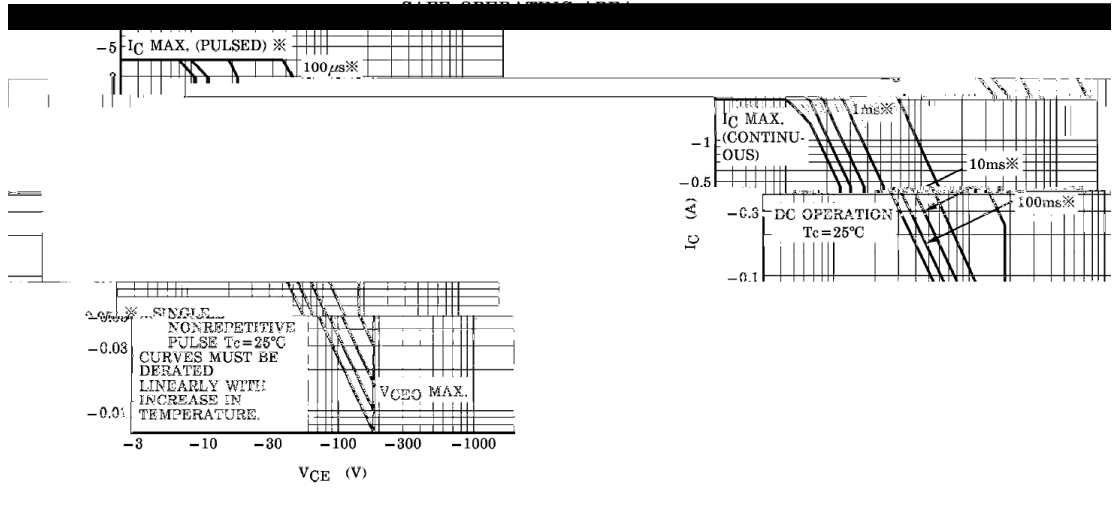
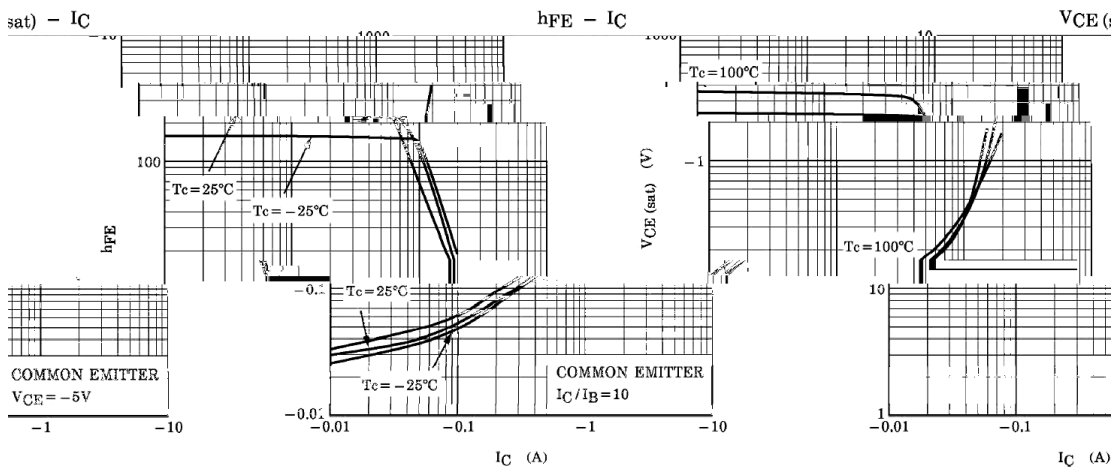
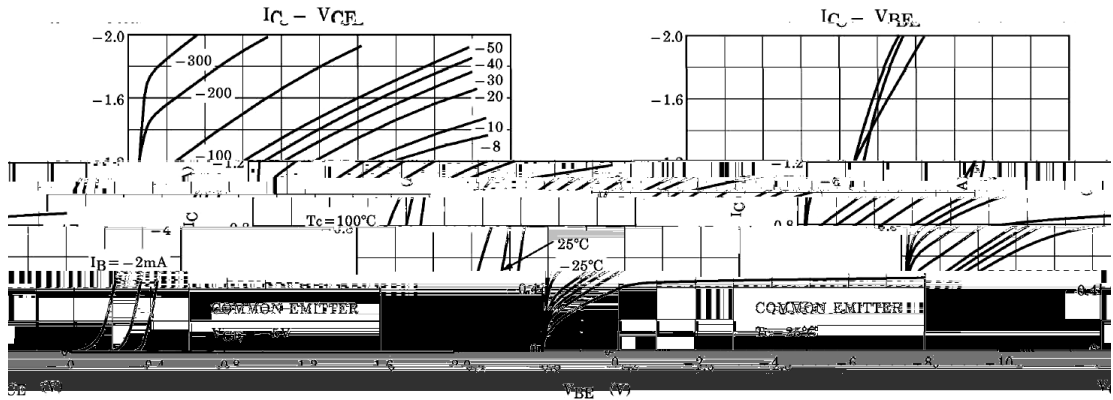
/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-180	V
Collector to Emitter Voltage	V_{CEO}	-180	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-2.0	A
Base Current - Continuous	I_B	-1.0	A
Collector Power Dissipation	P_C	1.5	W
Collector Power Dissipation	$P_C(T_c=25)$	20	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

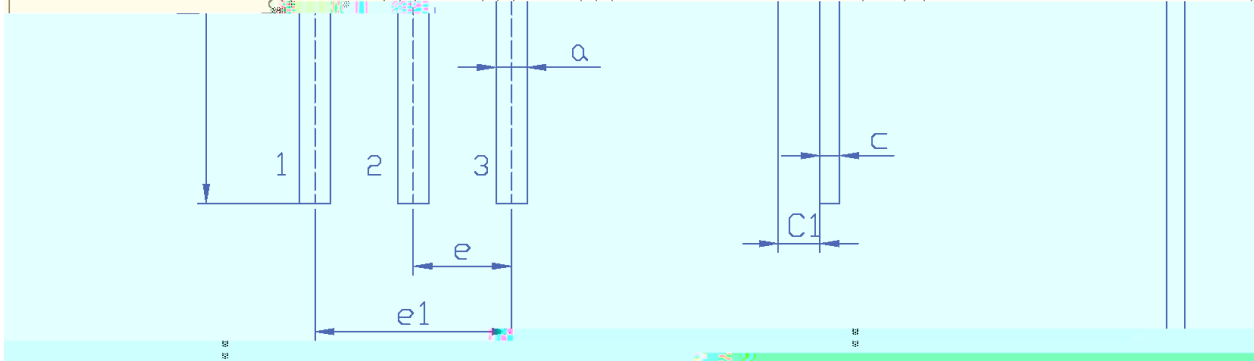
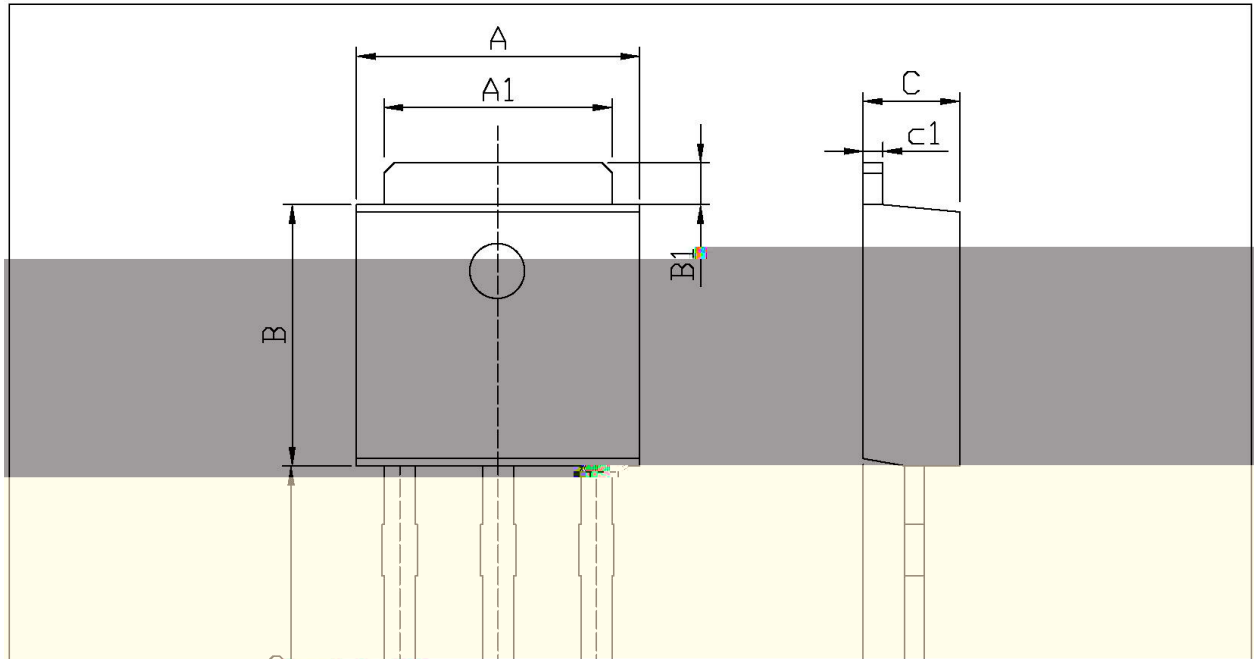
/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=-10mA$ $I_B=0$	-180			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=-180V$ $I_E=0$			-5.0	A
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=-5.0V$ $I_C=0$			-5.0	A
DC Current Gain	$h_{FE(1)}$	$V_{CE}=-5.0V$ $I_C=-100mA$	100		320	
	$h_{FE(2)}$	$V_{CE}=-5.0V$ $I_C=-1.0A$	50			
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-1.0A$ $I_B=-100mA$		-0.24	-1.0	V
Base to Emitter Voltage	V_{BE}	$V_{CE}=-5.0V$ $I_C=-1.0A$		-0.68	-1.5	V
Transition Frequency	f_T	$V_{CE}=-5.0V$ $I_C=-300mA$		200		MHz
Collector output capacitance	C_{ob}	$V_{CB}=-10V$ $I_E=0$ $f=1.0MHz$		26		pF

/ Electrical Characteristic Curve



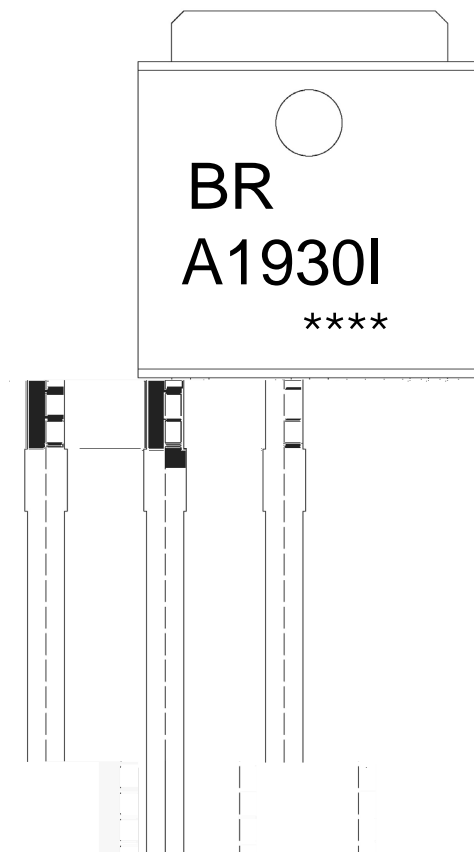
/ Package Dimensions



5.10	5.50	b	9.00	9.40		A1
5.95	6.35	c	0.45	0.55		B1
0.95	1.25	c1	0.45	0.55		B1
2.20	2.40	e	2.24	2.34		C
0.95	1.15	e1	4.43	4.73		C1

TO-251

/ Marking Instructions



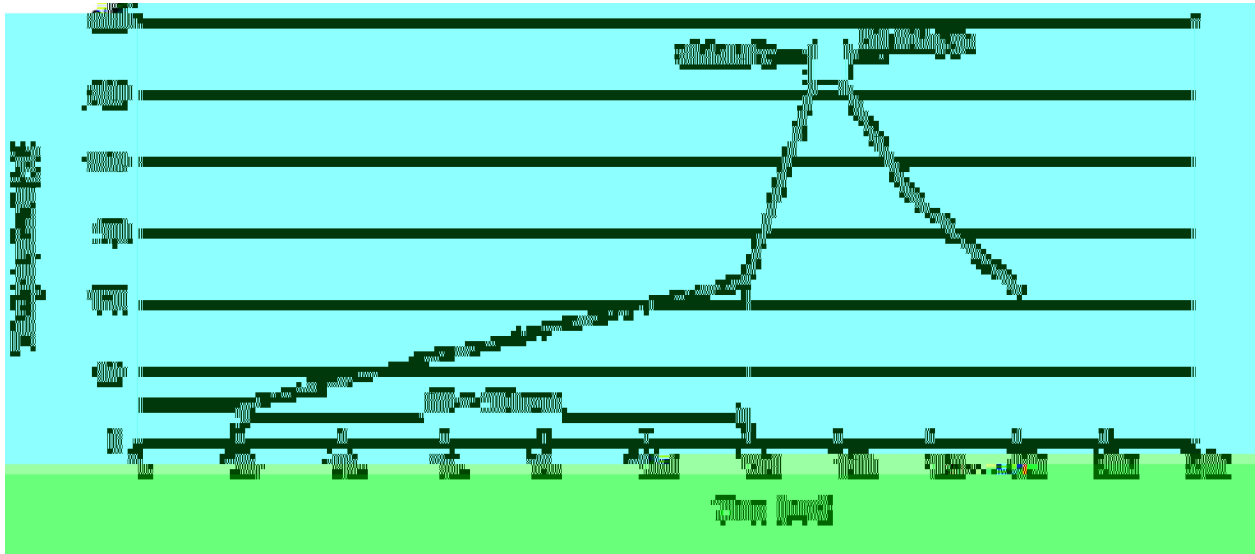
Note:

BR: Company Code

A1930I: Product Type.

****: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- | | | | | | |
|---|-----|-----|----|----------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 255 | 5 | 5 | 0.5sec; | 2.Peak Temp.:255 5 , Duration:5 0.5sec. |
| 3 | | | 2 | 10 /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

270 5 10 1 sec. Temp.:270±5 Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type	Units		Dimension	(unit mm ³)
	Units/Bag	Bags/Inner Box	Units/Inner Box	
	/	/	/	